# NUP2114 Series, SNUP2114

# **ESD Protection Diode**

# Low Capacitance ESD Protection for High Speed Data

The NUP2114 surge protection is designed to protect high speed data lines from ESD. Ultra-low capacitance and high level of ESD protection makes this device well suited for use in USB 2.0 applications.

# Features

- Low Capacitance 0.8 pF
- Low Clamping Voltage
- Stand Off Voltage: 5 V
- Low Leakage
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body model and Class C (Exceeding 400 V) per Machine Model
- Protection for the Following IEC Standards: IEC 61000-4-2 Level 4 ESD Protection
- UL Flammability Rating of 94 V-0
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

# **Typical Applications**

- High Speed Communication Line Protection
- USB 2.0 High Speed Data Line and Power Line Protection
- Monitors and Flat Panel Displays
- MP3
- Gigabit Ethernet
- Notebook Computers
- Digital Video Interface (DVI) and HDMI

# MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Operating Junction Temperature Range	ТJ	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Seconds)	ΤL	260	°C
Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Contact IEC61000-4-2 Air	ESD	16000 400 13000 15000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

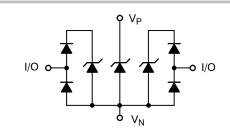
See Application Note AND8308/D for further description of survivability specs.



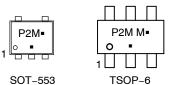
# **ON Semiconductor®**

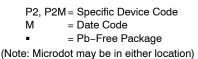
# www.onsemi.com



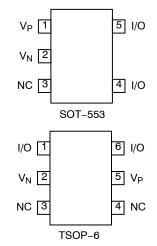


### MARKING DIAGRAMS





# **PIN CONNECTIONS**



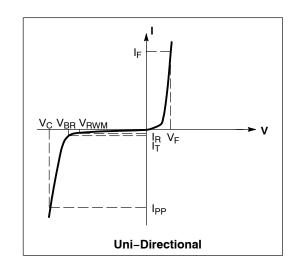
# **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

# **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
V <sub>RWM</sub>	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
Ι <sub>Τ</sub>	Test Current
١ <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>
P <sub>pk</sub>	Peak Power Dissipation
С	Max. Capacitance @ $V_R = 0$ and f = 1.0 MHz



\*See Application Note AND8308/D for detailed explanations of datasheet parameters.

Parameter	Symbol	Conditions		Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 1)			5.0	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1 mA, (Note 2)	5.5	7.5		V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5 V		0.01	1.0	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5 A (Note 3)		9.0		V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 8 A (Note 3)		10		V
Maximum Peak Pulse Current	I <sub>PP</sub>	8x20 μs Waveform			12	А
Junction Capacitance	CJ	$V_R = 0 V$ , f = 1 MHz between I/O Pins and GND		0.8	1.0	pF
Junction Capacitance	CJ	V <sub>R</sub> = 0 V, f = 1 MHz between I/O Pins			0.5	pF
Clamping Voltage	V <sub>C</sub>	@ I <sub>PP</sub> = 1 A (Note 4)			12	V
Clamping Voltage	V <sub>C</sub>	Per IEC 61000-4-2 (Note 5)	Fi	gures 1 and	2	V

ELECTRICAL CHARACTERISTICS (TJ=25°C unless otherwise specified)

1. Surge protection devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater than the DC or continuous peak operating voltage level.

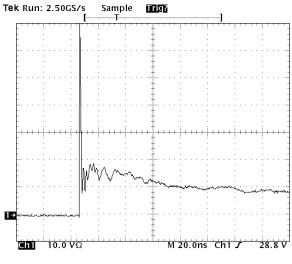
2. V<sub>BR</sub> is measured at pulse test current I<sub>T</sub>.

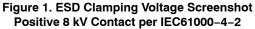
3. Nonrepetitive current pulse (Pin 5 to Pin 2)

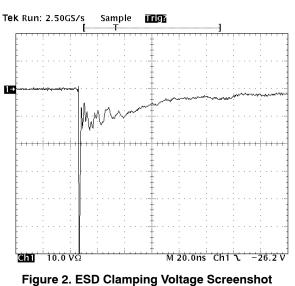
4. Surge current waveform per Figure 5.

5. Typical waveform. For test procedure see Figures 3 and 4 and Application Note AND8307/D.

6. Include S-prefix devices where applicable.





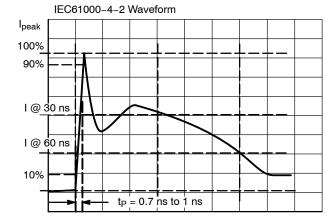


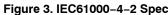
Negative 8 kV Contact per IEC61000-4-2

# NUP2114 Series, SNUP2114

#### IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8





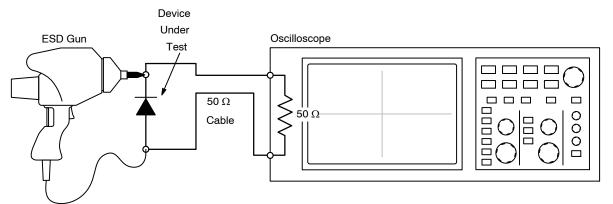


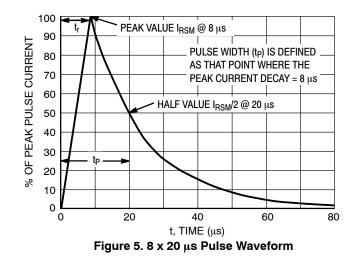
Figure 4. Diagram of ESD Test Setup

# The following is taken from Application Note AND8308/D – Interpretation of Datasheet Parameters for ESD Devices.

### **ESD Voltage Clamping**

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000–4–2 waveform. Since the IEC61000–4–2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.





# NUP2114 Series, SNUP2114

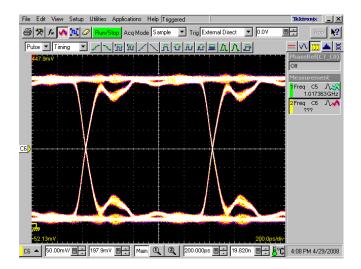


Figure 6. 500 MHz Data Pattern

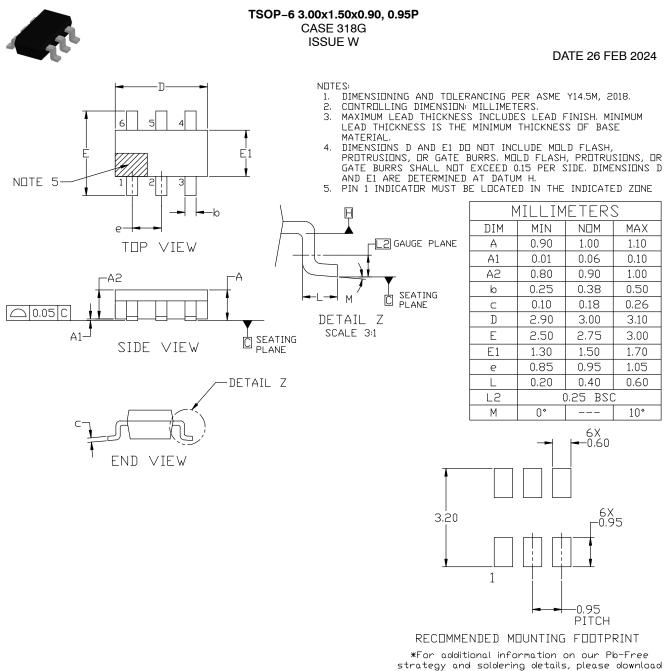
## **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
NUP2114UPXV5T1G	P2	SOT-553 (Pb-Free)	4,000 / Tape & Reel
NUP2114UCMR6T1G	P2M	TSOP-6 (Pb-Free)	3,000 / Tape & Reel
SNUP2114UCMR6T1G*	P2M	TSOP-6 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.





strategy and soldering details, please download th e DN Semiconductor Soldering and Mounting Techniques Reference manual, SDLDERRM/D.

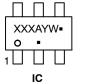
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DATE 26 FEB 2024

## GENERIC **MARKING DIAGRAM\***





XXX = Specific Device Code

= Pb-Free Package

= Date Code

XXX = Specific Device Code

А =Assembly Location

= Year

Υ W = Work Week

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

М

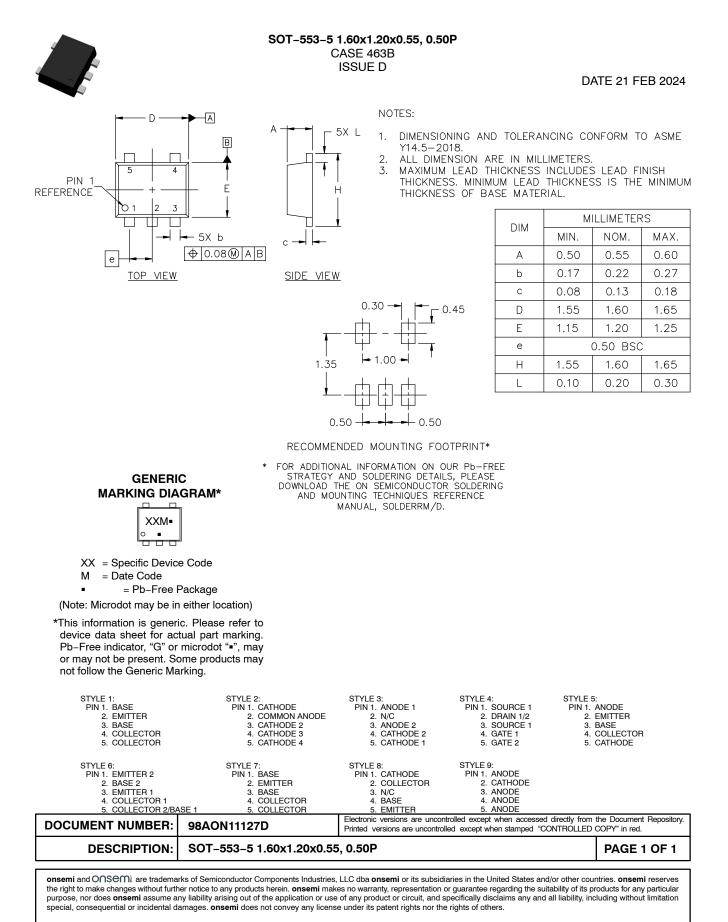
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STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. DRAIN	PIN 1. EMITTER 2	PIN 1. ENABLE	PIN 1. N/C	PIN 1. EMITTER 2	PIN 1. COLLECTOR
2. DRAIN	2. BASE 1	2. N/C	2. V in	2. BASE 2	2. COLLECTOR
3. GATE	3. COLLECTOR 1	3. R BOOST	3. NOT USED	3. COLLECTOR 1	3. BASE
4. SOURCE	4. EMITTER 1	4. Vz	4. GROUND	4. EMITTER 1	4. EMITTER
5. DRAIN	5. BASE 2	5. V in	5. ENABLE	5. BASE 1	5. COLLECTOR
6. DRAIN	6. COLLECTOR 2	6. V out	6. LOAD	6. COLLECTOR 2	6. COLLECTOR
STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:
PIN 1. COLLECTOR	PIN 1. Vbus	PIN 1. LOW VOLTAGE GATE	PIN 1. D(OUT)+	PIN 1. SOURCE 1	PIN 1. I/O
2. COLLECTOR	2. D(in)	2. DRAIN	2. GND	2. DRAIN 2	2. GROUND
3. BASE	3. D(in)+	3. SOURCE	3. D(OUT)-	3. DRAIN 2	3. I/O
4. N/C	4. D(out)+	4. DRAIN	4. D(IN)-	4. SOURCE 2	4. I/O
5. COLLECTOR	5. D(out)	5. DRAIN	5. VBUS	5. GATE 1	5. VCC
6. EMITTER	6. GND	6. HIGH VOLTAGE GATE	6. D(IN)+	6. DRAIN 1/GATE 2	6. I/O
STYLE 13: PIN 1. GATE 1 2. SOURCE 2 3. GATE 2 4. DRAIN 2 5. SOURCE 1 6. DRAIN 1	STYLE 14: PIN 1. ANODE 2. SOURCE 3. GATE 4. CATHODE/DRAIN 5. CATHODE/DRAIN 6. CATHODE/DRAIN		LE 16: 11. ANODE/CATHODE 2. BASE 3. EMITTER 4. COLLECTOR 5. ANODE 6. CATHODE	STYLE 17: PIN 1. EMITTER 2. BASE 3. ANODE/CATHODE 4. ANODE 5. CATHODE 6. COLLECTOR	

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